

# SOD-323 Plastic-Encapsulate Diodes

## BAP50-03 GENERAL PURPOSE PIN DIODE

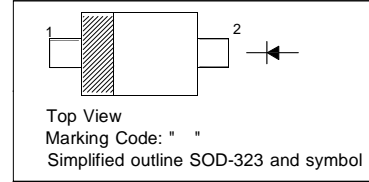
### FEATURES

- Low diode capacitance
- Low diode forward resistance

### MARKING: A81

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



### Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

Parameter	Symbol	Limit	Unit
Continuous Reverse Voltage	$V_R$	50	V
Continuous Forward Current	$I_F$	50	mA
Power Dissipation (Ta=90°C)	$P_d$	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	85	°C/W
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{STG}$	-55~+150	°C

### Electrical Ratings @Ta=25°C

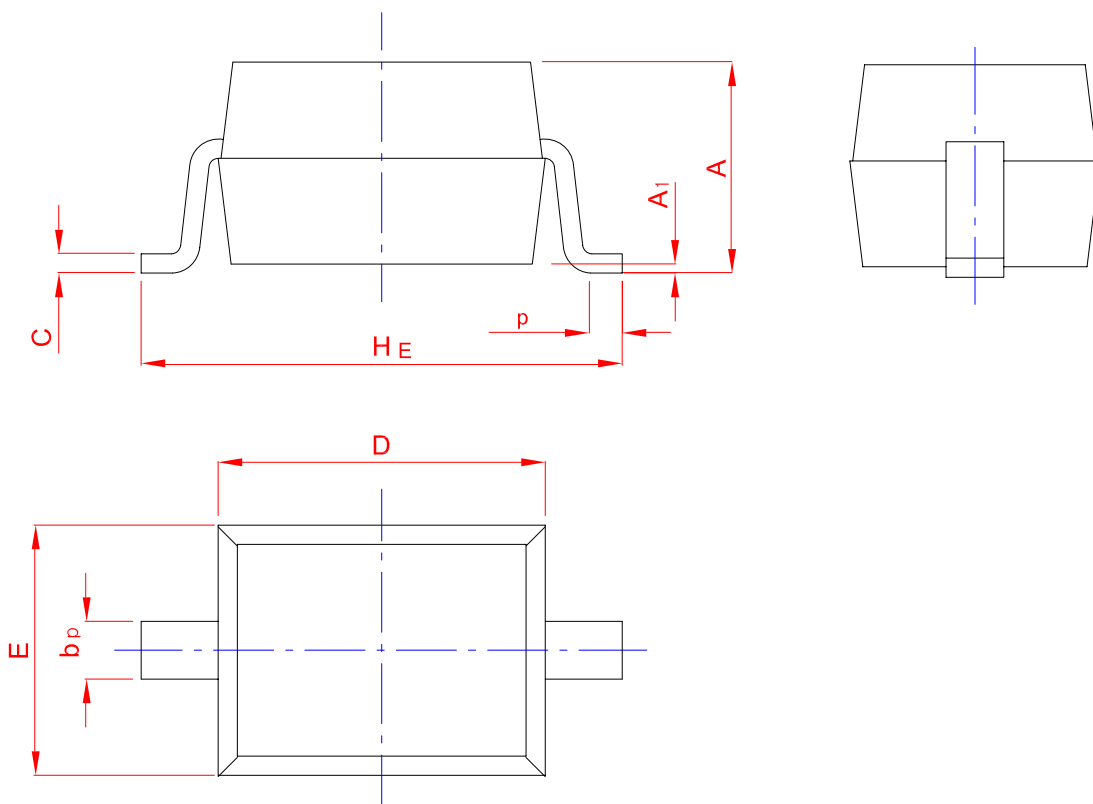
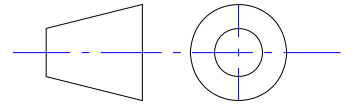
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Continuous reverse voltage	$V_R$	50			V	$I_R=10\mu A$
Forward voltage	$V_F$			1.1	V	$I_F=50mA$
Reverse current	$I_R$			100	nA	$V_R=50V$
Diode capacitance	$C_{d1}$			0.91	pF	$V_R=0V, f=1MHz$
	$C_{d2}$			0.55	pF	$V_R=1V, f=1MHz$
	$C_{d3}$			0.35	pF	$V_R=5V, f=1MHz$
Diode forward resistance	$r_D$			40	$\Omega$	$I_F=0.5mA, f=100MHz; note1$
	$r_D$			25	$\Omega$	$I_F=1mA, f=100MHz; note1$
	$r_D$			5	$\Omega$	$I_F=10mA, f=100MHz; note1$



## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>	A <sub>1</sub>	L <sub>p</sub>
mm	1.20	0.40	0.15	1.80	1.35	2.80	0.10	0.50
	0.90	0.25	0.10	1.60	1.15	2.30	0.01	0.20